

Special Issue:

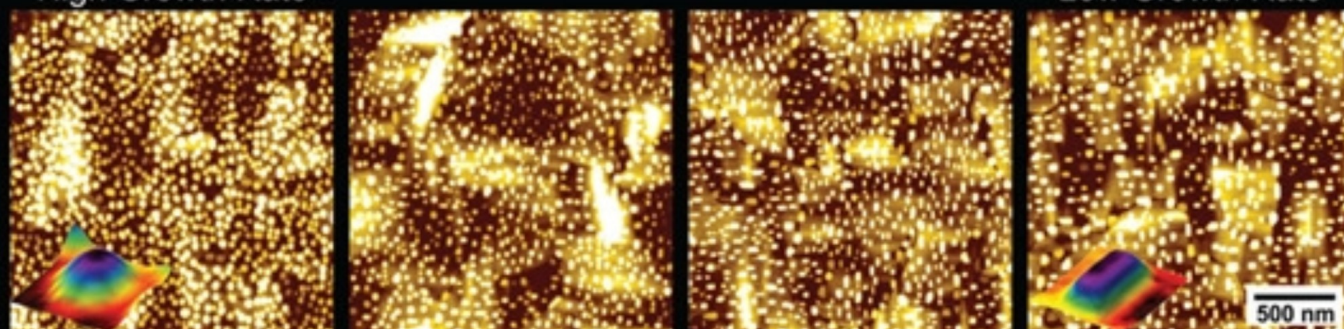
Compound Semiconductors

Guest-Edited by Srabanti Chowdhury,  
Tomas Palacios and Grace (Huili) Xing

GaSb/GaAs QDs on (001) Ge Substrate

High Growth Rate

Low Growth Rate



Circular-based

Rectangular-based

